Sheet, 1 , of 1 10/720,738										
INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)				Docket Number (Optional) FUJI:280 . SERIAL			NO.: NEW APPLICATION			
				APPLICANT(5) Akio SUGI et al.						
				FILING DATE: November 24, 2003			Group An Unit			
U.S. PATENT DOCUMENTS										
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLA	ASS	SUBCLASS	FILING DATE IF APPROPRIATE		
a	US	2002/0179967	12/02	Fujishima	257		330	*		
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FOREIGN PATENT DOCUMENTS										
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLA	ss	SUBCLASS	TRANSLATION		
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OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)										
Su			"A 30V Class Extremely Low On-resistance Meshed Trench Lateral Power MOSFET"; A SUGI et al.; IEEE 9/2002; pp. 297-300							
	1 1		a., 1000 7/2002, pp. 677-300							
										
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.